NSN 5961-01-003-5355

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View Online at https://aerobasegroup.com/nsn/5961-01-003-5355 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.315 inches **Overall Diameter:** 0.380 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 4 ferrule **Specification Data:** 80131-release 6293 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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